

MAPC-A1504

Rev. V2

Features

- MACOM PURE CARBIDE™ Amplifier Series
- · Suitable for Linear & Saturated Applications
- CW & Pulsed Operation: 500 W Output Power
- 260°C Reflow Compatible
- 50 V Operation
- 100% RF Tested
- RoHS* Compliant

Applications

- ISM
- Multi Market

Description

The MAPC-A1504 is a GaN on Silicon Carbide HEMT D-mode amplifier suitable for 1.2 - 1.4 GHz frequency operation. The device supports both CW and pulsed operation with minimum output power levels of 500 W (57 dBm) in an air cavity ceramic package.

Typical RF Performance:

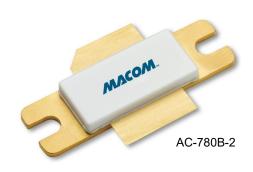
- Measured under load-pull at 2.5 dB Compression, 100 μs pulse width, 10% duty cycle.
- $V_{DS} = 50 \text{ V}, I_{DQ} = 380 \text{ mA}, T_{C} = 25^{\circ}\text{C}$

Frequency (GHz)	Output Power ¹ (dBm)	Gain ² (dB)	η _D ² (%)
1.2	58.3	17.9	74.6
1.3	58.3	18	73.5
1.4	58.2	18.1	73.1

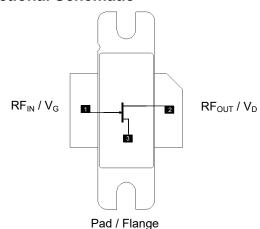
• $V_{DS} = 28 \text{ V}, I_{DQ} = 380 \text{ mA}, T_{C} = 25^{\circ}\text{C}$

Frequency (GHz)	Output Power ¹ (dBm)	Gain² (dB)	η _D ² (%)
1.2	55.3	16.4	71.3
1.3	55.2	16.7	71.1
1.4	55.1	16.2	70

- 1. Load impedance tuned for maximum output power.
- 2. Load impedance tuned for maximum drain efficiency.



Functional Schematic



Pin Configuration

Pin#	Pin Name	Function
1	RF _{IN} / V _G	RF Input / Gate
2	RF _{OUT} / V _D	RF Output / Drain
3	Flange ³	Ground / Source

The flange on the package bottom must be connected to RF, DC and thermal ground.

Ordering Information

Part Number	Package
MAPC-A1504-AB000	Bulk Quantity
MAPC-A1504-ABTR1	Tape and Reel
MAPC-A1504-ABSB1	Sample Board

^{*} Restrictions on Hazardous Substances, compliant to current RoHS EU directive.



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RF Electrical Characteristics: $T_C = 25^{\circ}C$, $V_{DS} = 50 \text{ V}$, $I_{DQ} = 380 \text{ mA}$ Note: Performance in MACOM Evaluation Test Fixture, 50Ω system

Parameter	Test Conditions	Symbol	Min.	Тур.	Max.	Units
Small Signal Gain	CW, 1.3 GHz	Gss	-	18.3	-	dB
Power Gain	CW, 1.3 GHz, 2.5 dB Gain Compression	G _{SAT}	-	15.8	-	dB
Saturated Drain Efficiency	CW, 1.3 GHz, 2.5 dB Gain Compression	η_{SAT}	-	70	-	%
Saturated Output Power	CW, 1.3 GHz, 2.5 dB Gain Compression	P _{SAT}	-	57.4	-	dBm
Gain Variation (-40°C to +85°C)	Pulsed ⁴ , 1.3 GHz	ΔG	-	0.2	-	dB/°C
Power Variation (-40°C to +85°C)	Pulsed ⁴ , 1.3 GHz	ΔP2.5dB	-	0.005	-	dB/°C
Power Gain	CW, 1.3 GHz, P _{IN} = 40.3 dBm	G _P	-	16.8	-	dB
Drain Efficiency	CW, 1.3 GHz, P _{IN} = 40.3 dBm	η	-	67	-	%
Input Return Loss	CW, 1.3 GHz, P _{IN} = 40.3 dBm	IRL	-	-18	-	dB
Ruggedness: Output Mismatch	Pulsed ⁴ , All phase angles	Ψ	VSWR = 10:1, No Damage		amage	
Ruggedness: Output Mismatch	CW , All phase angles	Ψ	VSWR = 7:1, No Damage		amage	

RF Electrical Specifications: T_A = 25°C, V_{DS} = 50 V, I_{DQ} = 380 mA Note: Performance in MACOM Production Test Fixture, 50 Ω system

Parameter	Test Conditions	Symbol	Min.	Тур.	Max.	Units
Power Gain	Pulsed ⁴ , 1.4 GHz, 2.5 dB Gain Compression	G _{SAT}	15.8	16.6	-	dB
Saturated Drain Efficiency	Pulsed ⁴ , 1.4 GHz, 2.5 dB Gain Compression	η_{SAT}	59.8	64.1	-	%
Saturated Output Power	Pulsed ⁴ , 1.4 GHz, 2.5 dB Gain Compression	P _{SAT}	56.8	57.4	-	dBm

^{4.} Pulse details: 100 μs pulse width, 10% Duty Cycle.

DC Electrical Characteristics: $T_A = 25$ °C

Parameter	Test Conditions	Symbol	Min.	Тур.	Max.	Units
Drain-Source Leakage Current	V_{GS} = -8 V, V_{DS} = 130 V	I _{DLK}	-	-	71.6	mA
Gate-Source Leakage Current	V_{GS} = -8 V, V_{DS} = 0 V	I _{GLK}	-	-	71.6	mA
Gate Threshold Voltage	V _{DS} = 50 V, I _D = 71.6 mA	V _T	-	-3.1	-	V
Gate Quiescent Voltage	$V_{DS} = 50 \text{ V}, I_{D} = 380 \text{ mA}$	V_{GSQ}	-	-2.5	-	V
Maximum Drain Current	V_{DS} = 7 V, pulse width 300 µs	I _{D, MAX}	-	85.2	-	Α



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Absolute Maximum Ratings^{5,6,7,8,9}

Parameter	Absolute Maximum
Drain Source Voltage, V _{DS}	130 V
Gate Source Voltage, V _{GS}	-10 to 3 V
Gate Current, I _G	71.6 mA
Storage Temperature Range	-65°C to +150°C
Case Operating Temperature Range	-40°C to +85°C
Channel Operating Temperature Range, T _{CH}	-40°C to +225°C
Absolute Maximum Channel Temperature	+250°C

- Exceeding any one or combination of these limits may cause permanent damage to this device.
- MACOM does not recommend sustained operation above maximum operating conditions.

- Operating at drain source voltage $V_{DS} < 55 \text{ V}$ will ensure MTTF > 2 x 10^6 hours.

 Operating at nominal conditions with $T_{CH} \le 225^{\circ}\text{C}$ will ensure MTTF > 2 x 10^6 hours.

 MTTF may be estimated by the expression MTTF (hours) = A $e^{\frac{[B+C/(T+273)]}{2}}$ where T is the channel temperature in degrees Celsius, A = 1, B = -38.215, and C = 26,343.

Thermal Characteristics¹⁰

Parameter	Test Conditions	Symbol	Typical	Units
Thermal Resistance using Finite Element Analysis	$V_{DS} = 50 \text{ V}$ $T_{C} = 85^{\circ}\text{C}, T_{CH} = 225^{\circ}\text{C}$	$R_{\theta}(FEA)$	0.420	°C/W
Thermal Resistance using Infrared Measurement of Die Surface Temperature	V _{DS} = 50 V T _C = 85°C,T _{CH} = 225°C	$R_{\theta}(IR)$	0.378	°C/W

^{10.} Case temperature measured using thermocouple embedded in heat-sink. Contact local applications support team for more details on this measurement.

Handling Procedures

Please observe the following precautions to avoid damage:

Static Sensitivity

Gallium Nitride Circuits are sensitive to electrostatic discharge (ESD) and can be damaged by static electricity. Proper ESD control techniques should be used when handling.



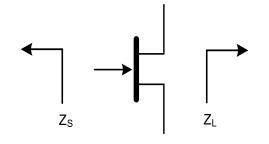
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Pulsed⁴ Load-Pull Performance @ 50 V: Reference Plane at Device Leads

		Maximum Output Power						
			V _{DS} = 50 V, I _{DQ} = 380 mA, T _C = 25°C, P2.5dB					
Frequency (GHz)	Z _{source} (Ω)	Z _{LOAD} ¹¹ (Ω)	Gain (dB)	P _{OUT} (dBm)	P _{OUT} (W)	η₀ (%)	AM/PM (°)	
1.2	1.7 - j2.2	0.8 - j0.2	16.9	58.3	676	63.7	16.6	
1.3	2.5 - j0.9	0.8 - j0.3	17	58.3	676	63.3	-26.6	
1.4	1.3 - j0.1	0.8 - j0.4	17	58.2	660.7	62.3	-73	

		Maximum Drain Efficiency						
			V _{DS} = 50 V, I _{DQ} = 380 mA, T _C = 25°C, P2.5dB					
Frequency (GHz)	Z _{SOURCE} (Ω)	Z _{LOAD} ¹² (Ω)	Gain (dB)	P _{OUT} (dBm)	P _{OUT} (W)	η _□ (%)	AM/PM (°)	
1.2	2.6 - j1.9	0.9 + j0.7	17.9	55.7	371.5	74.6	-21.8	
1.3	1.9 - j0.1	0.9 + j0.5	18	56.3	426.5	73.5	-70.7	
1.4	0.8 - j0.1	0.8 + j0.3	18.1	56.3	426.5	73.1	-107.3	

Impedance Reference



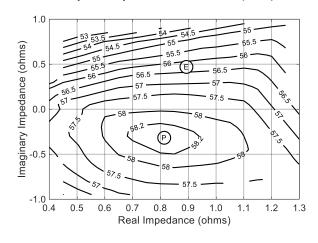
- $$\begin{split} Z_{\text{SOURCE}} &= \text{Measured impedance presented to the input of the} \\ \text{device at package reference plane.} \\ Z_{\text{LOAD}} &= \text{Measured impedance presented to the output of the} \end{split}$$
- device at package reference plane.
- 11. Load Impedance for optimum output power.12. Load Impedance for optimum efficiency.



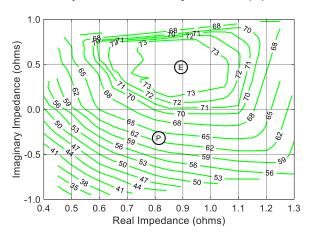
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Pulsed⁴ 50 V Load-Pull Performance @ 1.3 GHz

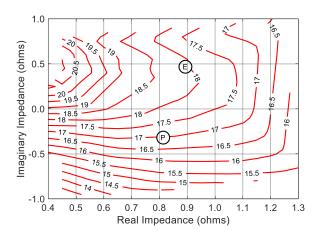
P2.5dB Loadpull Output Power Contours (dBm)



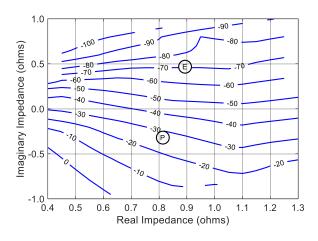
P2.5dB Loadpull Drain Efficiency Contours (%)



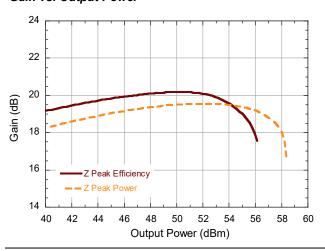
P2.5dB Loadpull Gain Contours (dB)



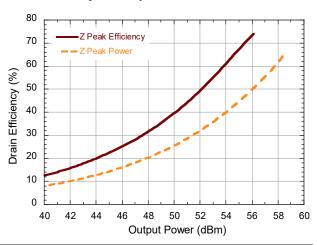
P2.5dB Loadpull AM/PM Contours (°)



Gain vs. Output Power



Drain Efficiency vs. Output Power



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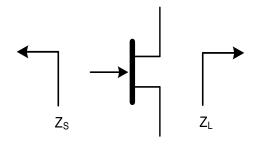
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Pulsed⁴ Load-Pull Performance at 28 V: Reference Plane at Device Leads

		Maximum Output Power						
			V _{DS} = 28 V, I _{DQ} = 380 mA, T _C = 25°C, P2.5dB					
Frequency (GHz)	Z _{source} (Ω)	Z _{LOAD} ¹¹ (Ω)	Gain (dB)	P _{OUT} (dBm)	P _{OUT} (W)	η₀ (%)	AM/PM (°)	
1.2	1.6 - j2.3	0.5 - j0.4	15.6	55.3	338.8	62.2	26.1	
1.3	2.9 - j1.0	0.5 - j0.6	15.6	55.2	331.1	58.8	-13.4	
1.4	1.5 + j0	0.5 - j0.7	15.6	55.1	323.6	58.4	-65.1	

		Maximum Drain Efficiency						
		V _{DS} = 28 V, I _{DQ} = 380 mA, T _C = 25°C, P2.5dB						
Frequency (GHz)	Z _{SOURCE} (Ω)	Z _{LOAD} ¹² (Ω)	Gain (dB)	P _{OUT} (dBm)	P _{OUT} (W)	η _□ (%)	AM/PM (°)	
1.2	2.5 - j1.7	0.8_ j0.3	16.4	52.2	166	71.3	-29.1	
1.3	2.1 + j0.2	0.8 + j0.1	16.7	52.2	166	71.1	-77.3	
1.4	0.8 - j0.2	0.8 - j0	16.2	52.4	173.8	70	-104.7	

Impedance Reference



Z_{SOURCE} = Measured impedance presented to the input of the device at package reference plane.

 Z_{LOAD} = Measured impedance presented to the output of the device at package reference plane.

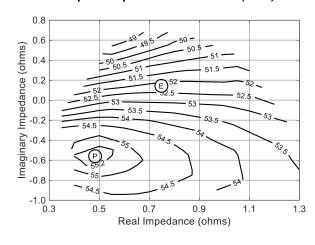
- 11. Load Impedance for optimum output power.
- 12. Load Impedance for optimum efficiency.



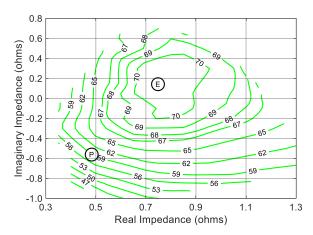
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Pulsed⁴ 28 V Load-Pull Performance @ 1.3 GHz

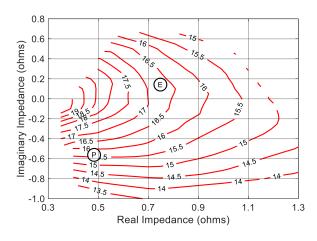
P2.5dB Loadpull Output Power Contours (dBm)



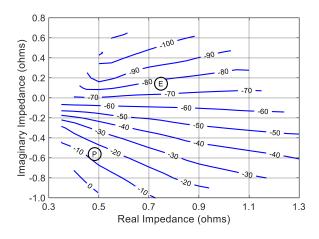
P2.5dB Loadpull Drain Efficiency Contours (%)



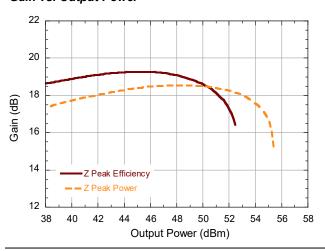
P2.5dB Loadpull Gain Contours (dB)



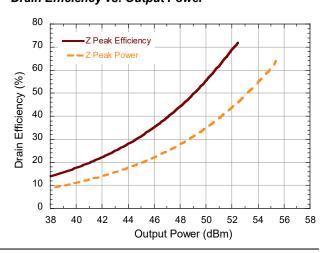
P2.5dB Loadpull AM/PM Contours (°)



Gain vs. Output Power



Drain Efficiency vs. Output Power



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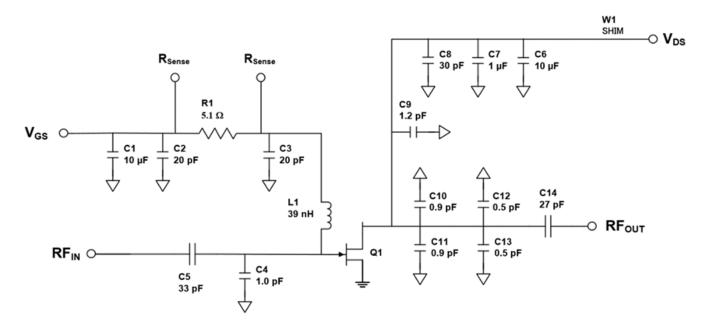
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Evaluation Test Fixture and Recommended Tuning Solution 1.2 - 1.4 GHz



Description

Parts measured on evaluation board (25-mil thick RO6010). Matching is provided using a combination of lumped elements and transmission lines as shown in the simplified schematic above. Recommended tuning solution component placement, transmission lines, and details are shown on the next page.

Bias Sequencing Turning the device ON

- 1. Set V_{GS} to pinch-off (V_P).
- 2. Turn on V_{DS} to nominal voltage (50 V).
- 3. Increase V_{GS} until I_{DS} current is reached.
- 4. Apply RF power to desired level.

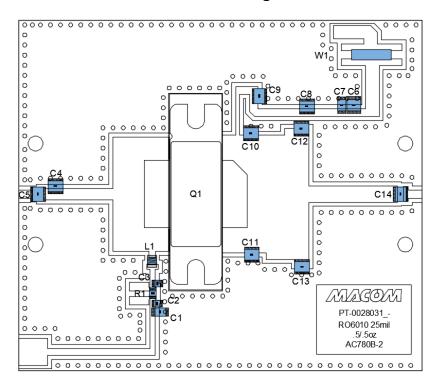
Turning the device OFF

- 1. Turn the RF power OFF.
- 2. Decrease $\,V_{GS}\,$ down to $\,V_{P}$ pinch-off.
- 3. Decrease V_{DS} down to 0 V.
- 4. Turn off V_{GS} .



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Evaluation Test Fixture and Recommended Tuning Solution 1.2 - 1.4 GHz

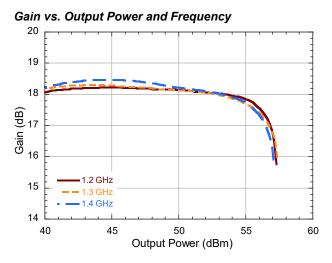


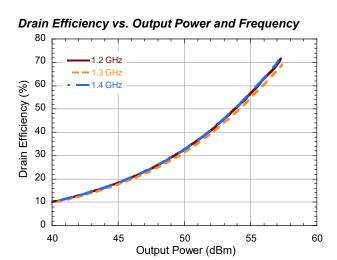
Reference Designator	Value	Tolerance	Manufacturer	Part Number		
C1	10 μF	+/- 10 %	Murata	GRM32EC72A106KE05L		
C2, C3	20 pF	+/- 5 %	PPI	0805N200JW251X		
C4	1.0 pF	+/- 0.1 pF	PPI	1111N1R0BW501XT		
C5	33 pF	+/- 5 %	PPI	1111N330JW501XT		
C6	10 μF	+/- 10 %	Murata	GRM32EC72A106KE05L		
C7	1 μF	+/- 10 %	Murata	GRM31CR72A105KA01L		
C8	30 pF	+/- 10 %	PPI	1111N300JW501XT		
C9	1.2 pF	+/- 0.1 pF	PPI	1111N1R2BW501XT		
C10, C11	0.9 pF	+/- 0.1 pF	PPI	1111N0R9BW501XT		
C12, C13	0.5 pF	+/- 0.1 pF	PPI	1111N0R5BW501XT		
C14	27 pF	+/- 0.1 pF	PPI	1111N270JW501XT		
R1	5.1 Ω	+/- 1 %	Vishay	CRCW08055R10FKEA		
L1	39 nH	+/- 5 %	Coilcraft	0805CS-390XJE		
W1	-	-	-	Copper Shim		
Q1	MACOM GaN Power Amplifier			MAPC-A1504		
PCB	RO6010, 25 mil, 0.5 oz. Cu, SnPb Finish					

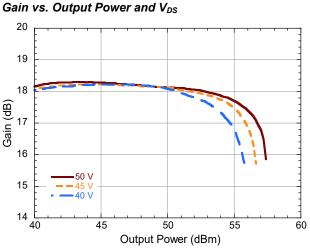


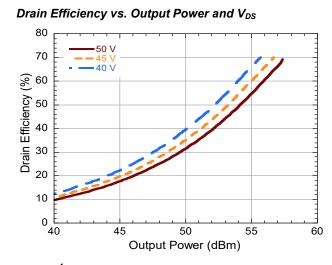
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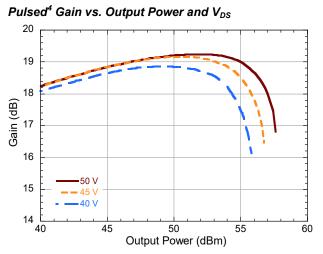
Typical Performance Curves as Measured in the 1.2 - 1.4 GHz Evaluation Test Fixture: CW 1.3 GHz, V_{DS} = 50 V, I_{DQ} = 380 mA, T_{C} = 25°C (Unless Otherwise Noted)

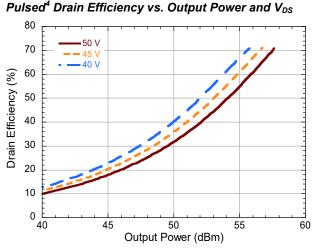












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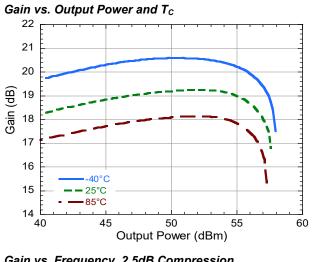
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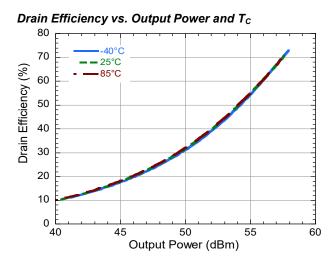
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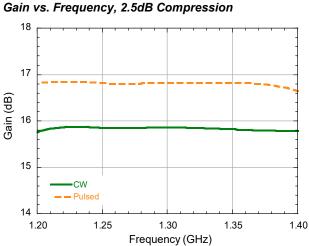


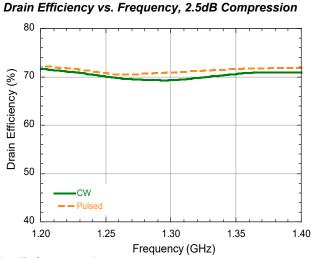
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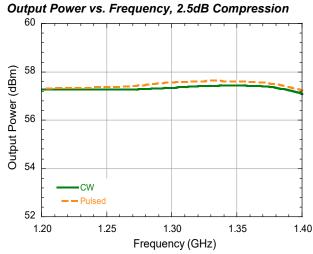
Typical Performance Curves as Measured in the 1.2 - 1.4 GHz Evaluation Test Fixture: Pulsed⁴ 1.3 GHz, V_{DS} = 50 V, I_{DQ} = 380 mA, T_{C} = 25°C (Unless Otherwise Noted)









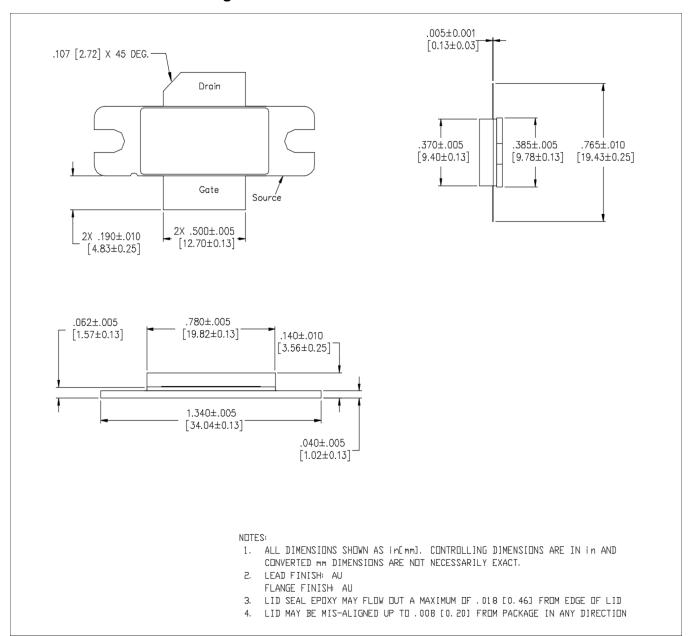




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Lead-Free AC-780B-2 Package Dimensions[†]



Reference Application Note AN0004363 for mounting recommendations. Meets JEDEC moisture sensitivity level 3 requirements. Plating is Au.

GaN Amplifier 50 V, 500 W 1.2 - 1.4 GHz



MACOM PURE CARBIDE

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